

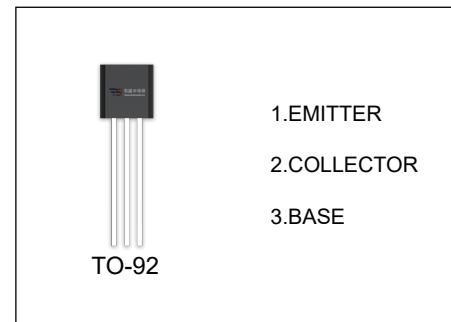
BC368 TRANSISTOR (NPN)

FEATURES

- High Current
- Low Voltage

APPLICATIONS

- General Purpose Switching and Amplification



ORDERING INFORMATION

| Part Number | Package | Packing Method | Pack Quantity |
|-------------|---------|----------------|---------------|
| BC368 | TO-92 | Bulk | 1000pcs/Bag |
| BC368-TA | TO-92 | Tape | 2000pcs/Box |

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|-----------------|--|----------|-----------------------------|
| V_{CBO} | Collector-Base Voltage | 25 | V |
| V_{CEO} | Collector-Emitter Voltage | 20 | V |
| V_{EBO} | Emitter-Base Voltage | 5 | V |
| I_C | Collector Current -Continuous | 1 | A |
| P_C | Collector Power Dissipation | 0.625 | W |
| $R_{\theta JA}$ | Thermal Resistance From Junction To Ambient | 200 | $^{\circ}\text{C}/\text{W}$ |
| T_J, T_{stg} | Operation Junction and Storage Temperature Range | -55~+150 | $^{\circ}\text{C}$ |

$T_a=25\text{ }^\circ\text{C}$ unless otherwise specified

| Parameter | Symbol | Test conditions | Min | Typ | Max | Unit |
|--------------------------------------|---------------|---|-----|-----|-----|---------------|
| Collector-base breakdown voltage | $V_{(BR)CBO}$ | $I_C=0.1\text{mA}, I_E=0$ | 25 | | | V |
| Collector-emitter breakdown voltage | $V_{(BR)CEO}$ | $I_C=10\text{mA}, I_B=0$ | 20 | | | V |
| Emitter-base breakdown voltage | $V_{(BR)EBO}$ | $I_E=0.01\text{mA}, I_C=0$ | 5 | | | V |
| Collector cut-off current | I_{CBO} | $V_{CB}=25\text{V}, I_E=0$ | | | 10 | μA |
| Emitter cut-off current | I_{EBO} | $V_{EB}=5\text{V}, I_C=0$ | | | 10 | μA |
| DC current gain | $h_{FE(1)}$ | $V_{CE}=1\text{V}, I_C=0.5\text{A}$ | 85 | | 375 | |
| | $h_{FE(2)}$ | $V_{CE}=10\text{V}, I_C=5\text{mA}$ | 50 | | | |
| | $h_{FE(3)}$ | $V_{CE}=1\text{V}, I_C=1\text{A}$ | 60 | | | |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C=1\text{A}, I_B=0.1\text{A}$ | | | 0.5 | V |
| Base-emitter voltage | V_{BE} | $I_C=1\text{A}, V_{CE}=1\text{V}$ | | | 1 | V |
| Transition frequency | f_T | $V_{CE}=5\text{V}, I_C=10\text{mA}, f=35\text{MHz}$ | 65 | | | MHz |